## Gain-Switched **1064 nm** Picosecond Compact Laser **ANGIS**

### FEATURES

- > Ultra compact;
- > Integrated driver;
- > Air cooled;
- Passively or Actively Q-switched 880 nm Pump Laser;
- > No Semiconductor Modulator (SESAM);
- > No Mode Locking;
- > Cost-effective.

### APPLICATIONS

#### Scientific

- > Remote Laser Sensing;
- > Time Resolved fluorescence spectroscopy;
- > Laser induced acoustic wave generation;
- > OPO pumping;
- > Other spectroscopic applications;

#### Industrial

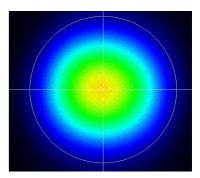
- Microprocessing of Dielectric Wafers, Silicon Wafers, Flexible Printed;
- Circuit Boards (FPCB), Printed Circuit Boards (PCB);
- > Flat Panes Display, LCD/LED/OLED Repair.





## Specifications

MODEL	ANGIS	
Pulse energy		
at 1064 nm	>100 uJ	
at 532 nm	>50 uJ	
at 355 nm	>30 uJ	
Typical pulse duration	<50 ps	
Energy stability (RMS)		
at 1064 nm	< 1.0 %	
at 532 nm	< 2.0 %	
at 355 nm	< 3.0 %	
Power drift	± 3.0 %	
Pulse repetition rate	Single shot - 10 kHz	
Beam profile	Gaussian	
Output beam diameter		
1064 nm	2.5±0.5 mm	
M <sup>2</sup>	<1.2	
Polarization	Linear, horizontal at 1064 nm	
Spectral linewidth	SLM	
Beam pointing stability	< 10 urad	
Optical jitter	<100 ns	
DIMENSIONS	392 x 253 x 157 mm	

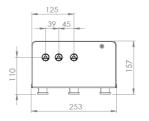


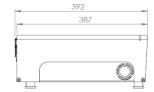
Typical beam intensity profile (20 cm from laser output) of ANGIS series lasers

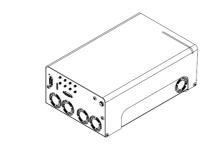
#### OPERATING REQUIREMENTS

Environmental operational conditions	Indoor use only	
Cooling requirements	Air cooled	
Ambient temperature	17 – 30 °C	
Relative humidity	10 - 65 %	
Mains voltage	100-230 VAC, single phase, 50-60 Hz	
Power consumption	< 60 W	

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ANGIS series laser head dimensions (in mm)

# Gain-Switched **880 nm** Nanosecond Laser **AGRIUS**

### FEATURES

- $\,$  > True Three Level Nd dopped Laser 10  $\mu J$  pulse energy at 880~nm
- > Short pulse duration < 1 ns (Passively QS) and < 0.5 ns Actively QS
- > Repetition Rate up to 10 kHz
- > Second Harmonics 440 nm

### Specifications

MODEL	AGRIUS		
Pulse energy			
at 880 nm	>10 uJ		
at 440 nm	> 5 uJ		
Pulse duration	1 ns		
Energy stability (RMS)			
at 880 nm	< 1.0 %		
at 440 nm	< 2.0 %		
Power drift	± 1.0 %		
Pulse repetition rate	Single shot – 10 kHz		
Beam profile	Gaussian		
Output beam diameter			
880 nm	1.5±0.5 mm		
M <sup>2</sup>	< 1.2		
Polarization	Linear, horizontal at 880 nm		
Spectral linewidth	SLM		
Beam pointing stability	< 10 urad		
Optical jitter	< 100 ns		
DIMENSIONS	392 x 253 x 157 mm		
OPERATING REQUIREM	ENTS		
Environmental operational conditions	Indoor use only		
Cooling requirements	Air cooled		
Ambient temperature	17 – 30 °C		
Relative humidity	10 - 65 %		
POWER			
Mains voltage	100-230 VAC, single phase, 50-60 Hz		





# Diode Pumped Picosecond Passively Q-Switched Laser MPL2210

### FEATURES

- > More than 2 mJ pulse energy at 1064 nm
- > Short pulse duration < 250-270 ps
- > 1 100 Hz repetition rate
- Vltra-compact
- Passively Q-switched
- > Average power 200 mW
- > High peak power > 7 MW
- > Guaranteed > 3 Gshot lifetime
- > Other wavelengths (e.g. 532 nm, 355 nm, 266 nm) are available

### MPL2210 series DPSS passively

Q-switched picosecond laser deliver high peak powers > 7 MW at 100 Hz repetition rate. Short laser cavity is fixed on thermo- stabilized and controlled baseplate which gives extremely stable output parameters performance. Small footprint is welcome point for integration into OEM lasers. Sub- nanosecond pulse duration of < 250-270 ps, high pulse energy more than 2 mJ, variable repetition rate from 1 Hz to 100 Hz covers many applications like pollution monitoring, DNA analysis, supercontinuum generation and many others.

Due to short pulse duration and high pulse energy laser delivers high peak power which is up to 7 MW. Optional conversion to green (532 nm) and ultraviolet (355 nm, 266 nm) is also available.

### APPLICATIONS

- > Seeder for amplifiers
- > Skincare
- Laser-induced breakdown spectroscopy (LIBS)
- > Time resolved fluorescence measurements
- > DNA analysis
- > Pollution monitoring
- > Remote sensing
- > Supercontinuum generation
- > Ignition of gas mixtures





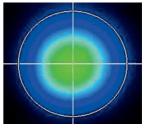
## QS LASERS

### Specifications <sup>1)</sup>

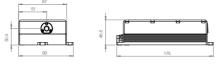
MODEL	MPL2210	
Pulse energy		
at 1064 nm	2 mJ	
at 532 nm	1 mJ	
at 355 nm	0.5 mJ	
at 266 nm	0.25 mJ	
Typical pulse duration	< 250 ps - 270 ps <sup>2)</sup>	
Pulse to pulse energy stability	ty (RMS)	
at 1064 nm	< 1.0 % <sup>3</sup> )	
at 532 nm	< 2.0 % <sup>3</sup> )	
at 355 nm	< 3.0 % <sup>3)</sup>	
at 266 nm	< 4.0 % <sup>3)</sup>	
Power drift	± 3.0 % <sup>4)</sup>	
Pulse repetition rate 5)	1 – 100 Hz	
Beam profile	close to Gaussian	
Beam divergence 6)	< 6 mrad	
Polarization	linear, horizontal at 1064 nm	
Spectral linewidth	SLM	
Beam pointing stability 7)	< 10 µrad	
Typical beam diameter <sup>8)</sup>	1.5 mm	
Optical jitter	~ 2 µs RMS <sup>9</sup>	
DIMENSIONS		
Logar bood (Myd yll)	125 × 295 × 76 mm (with harmonics)	
Laser head (W×L×H)	99 × 174 × 45.5 mm (OEM version)	
Controller unit (Wyl yH)	257 × 271 × 153 mm	
Controller unit (W×L×H)	75 × 200 × 70 mm (OEM version)	
OPERATING REQUIREMENT	S	
Cooling requirements	TEC	
Ambient temperature	20 – 25 °C	
Relative humidity	10 - 80 % (non-condensing)	
Mains voltage	100 – 230 VAC, single phase, 50 – 60 Hz <sup>10)</sup>	
Power consumption	< 20 W	

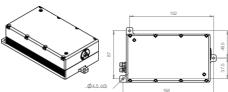
- <sup>1)</sup> Due to continuous improvements all specifications are subject to change. Unless stated otherwise all specifications are measured at 1064 nm.
- <sup>2)</sup> FWHM level at 1064 nm.
- <sup>3)</sup> Averaged from 60 seconds time interval in 5 series.
- <sup>4)</sup> Over 8-hour period after max 5 minutes of warm-up when ambient temperature variation is less than ±2 °C.
- Factory-set pulse repetition rate is fixed at 10 Hz repetition rate. Higher repetition rates are available, please inquire for more details.
- Full angle measured at the 1/e<sup>2</sup> level. Lower beam divergence is available upon request, please inquire for more details.
- RMS value measured from 1000 shots.
- <sup>8)</sup> Beam diameter is measured 20 cm from laser output at the 1/e<sup>2</sup> level.
- <sup>9)</sup> In respect to Q-switch triggering rising edge pulse.
- Laser can be powered from appropriate 12 VDC power source. Inquire for details.

	DANGER
1	VISIBLE AND/OR INVISIBLE LASER RADIATION AVOID EYE OR SKIN EXPOSURE TO DIRECT REFLECTED OR SCATTERED RADIATION
不	Nd:YAG 1064 nm, 532 nm, 355 nm, 266 nm Max. 2 mJ, pulse < 500 ps LD 800 nm, max 60 W CLASS IV LASER PRODUCT



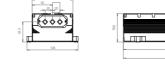
Typical beam intensity profile (20 cm from laser output) of MPL2210 series lasers

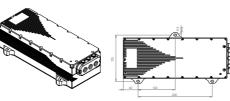




MPL2210 series laser head dimensions OEM version (in mm)

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MPL2210 series laser head dimensions (in mm)

HOTO www.phototechnica.co.jp
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 TEL:048-871-0067 FAX:048-871-0068

# Diode Pumped Picosecond Passively Q-Switched Lasers MPL2310 / MPL2510

### FEATURES

- > More than 2 mJ pulse energy at 1064 nm
- Short pulse duration < 500 ps</p>
- > 1 100 Hz repetition rate
- > Ultra-compact
- Passively Q-switched
- > Average power 200 mW
- > High peak power > 4 MW
- > Guaranteed > 3 Gshot lifetime
- > Other wavelengths (e.g. 532 nm, 355 nm) are available

### MPL2310 series DPSS passively

Q-switched picosecond lasers deliver high peak powers > **5 MW** at **100 Hz** repetition rate. Short laser cavity is fixed on thermostabilized and controlled baseplate which gives extremely stable output parameters performance. Small footprint is welcome point for integration into OEM lasers. Subnanosecond pulse duration of **< 350 ps**, high pulse energy more than **2 mJ**, variable repetition rate from 1 Hz to 100 Hz covers many applications like pollution monitoring, DNA analysis, supercontinuum generation and many others.

Due to short pulse duration and high pulse energy laser delivers high peak power which is up to 5 MW. Optional conversion to green (532 nm) and ultraviolet (355 nm, 266 nm) is also available.

### APPLICATIONS

- > Seeder for amplifiers
- > Skincare
- Laser-induced breakdown spectroscopy (LIBS)
- > Time resolved fluorescence measurements
- > DNA analysis
- > Pollution monitoring
- > Remote sensing
- Supercontinuum generation Ignition of gas mixtures





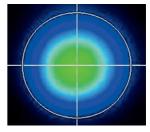
## QS LASERS

### Specifications <sup>1)</sup>

MODEL	MPL2310 / MPL2510	MPL1310 / MPL1510	
Pulse energy			
at 1064 nm	2 mJ	1 mJ	
at 532 nm	1 mJ	0.5 mJ	
at 355 nm	0.5 mJ	0.25 mJ	
at 266 nm	0.25 mJ	0.15 mJ	
Typical pulse duration	<350 ps/ <500 ps <sup>2)</sup>		
Pulse to pulse energy stability	y (RMS)		
at 1064 nm	< 1.0 % <sup>3</sup> )		
at 532 nm	< 2.0	<b>)</b> % <sup>3)</sup>	
at 355 nm	< 3.0 % <sup>3)</sup>		
at 266 nm	< 4.0	9 % <sup>3)</sup>	
Power drift	± 3.0 % <sup>4)</sup>		
Pulse repetition rate <sup>5)</sup>	1 – 100 Hz		
Beam profile	close to Gaussian		
Beam divergence 6)	< 6 mrad		
Polarization	linear, horizontal at 1064 nm		
Spectral linewidth	SLM		
Beam pointing stability 7)	< 10 µrad		
Typical beam diameter <sup>8)</sup>	1.5 mm		
Optical jitter	~ 2 µs RMS <sup>9</sup>		
DIMENSIONS			
Looorbood (Mydydd)	125 × 295 × 76 mm (with harmonics)		
Laser head (W×L×H)	99 × 174 × 45.5 mm (OEM version)		
Controller unit (Wyl yl)	257 × 271 × 15 mm		
Controller unit (W×L×H)	75 × 200 × 70 m	m (OEM version)	
OPERATING REQUIREMENTS	3		
Cooling requirements	air cooled		
Ambient temperature	15 – 30 °C		
Relative humidity	10 - 80 % (non-condensing)		
Mains voltage	100 – 230 VAC, single phase, 50 – 60 Hz <sup>10)</sup>		

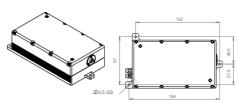
- Due to continuous improvements all specifications are subject to change. Unless stated otherwise all specifications are measured at 1064 nm.
- <sup>2)</sup> FWHM level at 1064 nm. Averaged from 60 seconds time interval in 5 series.
- <sup>3</sup> Over 8-hour period after max 5 minutes of warm-up when ambient temperature variation is less than ±2 °C.
- Factory-set pulse repetition rate is fixed at 100 Hz repetition rate. Higher repetition rates are available, please inquire for more details.
- Full angle measured at the 1/e<sup>2</sup> level. Lower beam divergence is available upon request, please inquire for more details.
- RMS value measured from 1000 shots.
- 7) Beam diameter is measured 20 cm from laser output at the 1/e<sup>2</sup> level.
- <sup>8)</sup> In respect to Q-switch triggering rising edge pulse.
- <sup>9)</sup> Laser can be powered from appropriate 12 VDC power source. Inquire for details.





Typical beam intensity profile (20 cm from laser output) of MPL2310 series lasers





MPL2310 series laser head dimensions OEM version (in mm)

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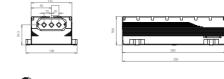
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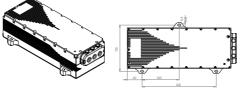
HOTO

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MPL2310 series laser head dimensions (in mm)

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 Naujoji Riovoniu str. 25B, Vilnius LT-03153, Lithuania

# Diode Pumped Sub-Nanosecond Actively Q-Switched Laser MPL15100

### FEATURES

- > More than 0.5 mJ pulse energy at 1064 nm
- > Short pulse duration < 700 ps
- > Up to 1 kHz repetition rate
- > 532 nm, 355 nm, 266 nm wavelengths as standard option
- Actively Q-Switched
- > Peak Power 0.7 MW
- Other wavelengths (e.g. 532 nm, 355 nm, 266 nm) are available

MPL15100 series robust DPSS actively Q-switched sub-nanosecond lasers deliver multi-kW peak powers, less than 1 ns pulse duration at 1 kHz repetition rate. Short innovative laser cavity with is fixed on thermostabilized baseplate which gives extremely stable output parameters performance. Small footprint is welcome point for integration into OEM lasers. Sub-nanosecond pulse duration of < 700 ps with near transform limited spectral linewidth at repetition rates up to 1 kHz with low timing jitter of < 200 ps and energies more than 500 µJ covers broad spectrum of applications starting from LIBS, laser induced fluorescence to many others. Standard optional harmonics generator to green (532 nm) and ultraviolet (355 nm, 266 nm) is also available.

### APPLICATIONS

- > Spectroscopy
- Marking
- > MALDI
- Seeding laser amplifiers
- Pollution Monitoring
- > Remote sensing



## QS LASERS

### Specifications <sup>1)</sup>

MODEL	MPL15100	MPL15100-1K
Pulse energy:		
at 1064 nm	0.5 mJ	
at 532 nm	0.25 mJ	
at 355 nm	0.15 mJ	
at 266 nm	0.1 mJ	
Typical pulse duration	< 700 ps <sup>2)</sup>	
Pulse to pulse energy stability (	RMS):	
at 1064 nm	< 0.5	<b>5 %</b> <sup>3)</sup>
at 532 nm	< 1.0 % <sup>3)</sup>	
at 355 nm	< 1.5 % <sup>3)</sup>	
at 266 nm	< 2.0 % <sup>3)</sup>	
Power drift	± 3.0 % <sup>4)</sup>	
Pulse repetition rate <sup>5)</sup>	100 Hz	1 kHz
Beam spatial profile	Close to Gaussian	
Beam divergence 6)	< 4 mrad	
Polarization	Linear, horizontal at 1064 nm	
Spectral linewidth	SLM	
Beam pointing stability 7)	< 50 µrad	
Typical beam diameter <sup>8)</sup>	1.2 mm	
Optical jitter	< 0.2 ns <sup>9)</sup>	
DIMENSIONS		
Laser head (W×L×H)	163 × 295 × 53.5 mm	
Controller unit (W×L×H)	257 × 271 × 153 mm	
Cable cord length	1 m	
OPERATING REQUIREMENTS		
Cooling requirements	air cooled	
Ambient temperature	15 – 30 °C	
Relative humidity	10 – 80 % (non-condensing)	
Mains voltage	100 – 240 VAC, single phase, 50 – 60 Hz	
Power consumption	< 10 W	< 100 W

<sup>1)</sup> Due to continuous improvements all specifications are subject to change. Unless stated otherwise all specifications are measured at 1064 nm.

<sup>2)</sup> FWHM level at 1064 nm.

<sup>3)</sup> Averaged from 60 seconds time interval.

<sup>4)</sup> Over 8-hour period after max 5 minutes of warm-up when ambient temperature variation is less than ±2 °C.

Factory-set pulse repetition rate is fixed at max repetition rate. Higher repetition rates are available, please inquire for details.

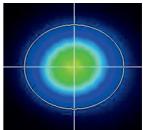
<sup>6)</sup> Full angle measured at the 1/e<sup>2</sup> level.

 7 RMS value measured from 1000 shots.

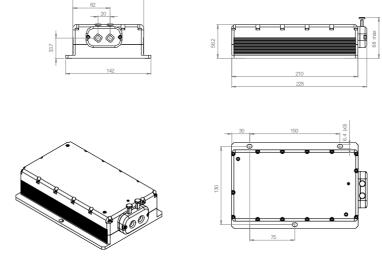
<sup>8)</sup> Beam diameter is measured 20 cm from laser output at the 1/e<sup>2</sup> level.

<sup>9)</sup> In respect to Q-switch triggering rising edge pulse.





Typical beam intensity profile (20 cm from laser output) of MPL15100 series lasers



MPL15100 laser head dimensions with attached harmonics unit (in mm)

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